## BAS316WS Silicon Epitaxial Planar Switching Diode

## Applications

- High-speed switching
PINNING

| PIN | DESCRIPTION |
| :---: | :--- |
| 1 | Cathode |
| 2 | Anode |



Top View
Marking Code: "A6"
Simplified outline SOD-323 and symbol

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Repetitive Peak Reverse Voltage | $\mathrm{V}_{\text {RRM }}$ | 100 | V |
| Reverse Voltage | $\mathrm{V}_{R}$ | 100 | V |
| Continuous Forward Current | $\mathrm{I}_{\mathrm{F}}$ | 250 | mA |
| Repetitive Peak Forward Current | $\mathrm{I}_{\text {FRM }}$ | 500 | mA |
| Non-Repetitive Peak Forward Surge Current <br> at tp=8.3ms,TA=25 ${ }^{\circ} \mathrm{C}$ | $\mathrm{I}_{\text {FSM }}$ | 2 | A |
| Total Power Dissipation | $\mathrm{P}_{\text {tot }}$ | 250 | mW |
| Junction Temperature | $\mathrm{T}_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | $-55 \mathrm{to}+150$ | ${ }^{\circ} \mathrm{C}$ |

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Max. | Unit |
| :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Forward Voltage } \\ & \text { at } I_{F}=1 \mathrm{~mA} \\ & \text { at } I_{F}=10 \mathrm{~mA} \\ & \text { at } I_{I^{\prime}}=50 \mathrm{~mA} \\ & \text { at } I_{F}=150 \mathrm{~mA} \end{aligned}$ | $V_{F}$ | $\begin{gathered} 0.715 \\ 0.855 \\ 1 \\ 1.25 \end{gathered}$ | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } V_{R}=25 \mathrm{~V} \\ & \text { at } V_{R}=75 \mathrm{~V} \end{aligned}$ | $\mathrm{I}_{\mathrm{R}}$ | $\begin{gathered} 30 \\ 1 \end{gathered}$ | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ |
| Diode Capacitance at $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{C}_{\text {tot }}$ | 1.5 | pF |
| Reverse Recovery Time at $I_{F}=I_{R}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{rr}}=0.1 \mathrm{XI} \mathrm{I}_{\mathrm{R}}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\mathrm{rr}}$ | 4 | ns |

## Typical Characteristics






## PACKAGE OUTLINE



